



INTERNATIONAL
GEMOLOGICAL
INSTITUTE

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LABORATORY GROWN DIAMOND REPORT

September 7, 2026

IGI Report Number

Description

Shape and Cutting Style

Measurements

LG830623992

LABORATORY GROWN DIAMOND

SQUARE EMERALD CUT

7.65 X 7.61 X 4.58 MM

GRADING RESULTS

Carat Weight

Color Grade

Clarity Grade

2.52 CARATS

E

VVS 1

ADDITIONAL GRADING INFORMATION

Polish

Symmetry

Fluorescence

EXCELLENT

EXCELLENT

NONE

Inscription(s)

Comments: As Grown - No indication of post-growth treatment.
This Laboratory Grown Diamond was created by High Pressure High Temperature (HPHT) growth process. Type II

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PROPORTIONS

Medium

12.5%

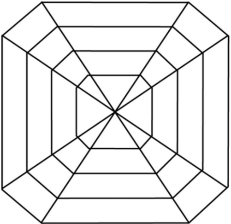
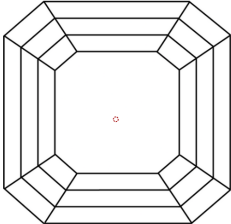
43.5%

66%

60.2%

Pointed

CLARITY CHARACTERISTICS



KEY TO SYMBOLS

Red symbols indicate internal characteristics.
Green symbols indicate external characteristics.

Sample Image Used



COLOR

D

E

F

G

H

I

J

Faint

Very Light

Light

CLARITY

FL

IF

VVS¹⁻²

VS¹⁻²

SI¹⁻²

I¹⁻³

Flawless

Internally Flawless

Very Very Slightly Included

Very Slightly Included

Slightly Included

Included

IGI

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